

**Vishay Semiconductors** 

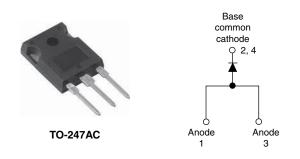
RoHS

COMPLIANT

HALOGEN

FREE

# Fast Soft Recovery Rectifier Diode, 80 A



PRODUCT SUMMARY				
Package	TO-247AC			
I <sub>F(AV)</sub>	80 A			
V <sub>R</sub>	1000 V, 1200 V			
V <sub>F</sub> at I <sub>F</sub>	1.35 V			
I <sub>FSM</sub>	1100 A			
t <sub>rr</sub>	90 ns			
T <sub>J</sub> max.	150 °C			
Diode variation	Single die			
Snap factor	0.5			

### **FEATURES**

- 150 °C max. operating junction temperature
- · Low forward voltage drop and short reverse recovery time
- Designed and qualified according to JEDEC-JESD47
- Compliant to RoHS Directive 2002/95/EC
- Halogen-free according to IEC 61249-2-21 definition (-M3 only)

## **APPLICATIONS**

These devices are intended for use in output rectification and freewheeling in inverters, choppers and converters as well as in input rectification where severe restrictions on conducted EMI should be met.

## DESCRIPTION

The VS-80APF1... soft recovery rectifier series has been optimized for combined short reverse recovery time and low forward voltage drop.

The glass passivation ensures stable reliable operation in the most severe temperature and power cycling conditions.

MAJOR RATINGS AND CHARACTERISTICS						
SYMBOL	TEST CONDITIONS	VALUES	UNITS			
V <sub>RRM</sub>		1000/1200	V			
I <sub>F(AV)</sub>	Sinusoidal waveform	80	٨			
I <sub>FSM</sub>		1100	A			
t <sub>rr</sub>	1 A, - 100 A/µs	90	ns			
V <sub>F</sub>	40 A, T <sub>J</sub> = 25 °C	1.2	V			
TJ		- 40 to 150	°C			

VOLTAGE RATINGS						
PART NUMBER	V <sub>RRM</sub> , MAXIMUM PEAK REVERSE VOLTAGE V	V <sub>RSM</sub> , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I <sub>RRM</sub> AT 150 °C mA			
VS-80APF10PbF, VS-80APF10-M3	1000	1100	12			
VS-80APF12PbF, VS-80APF12-M3	1200	1300	12			



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ABSOLUTE MAXIMUM RATINGS				
PARAMETER	SYMBOL	L TEST CONDITIONS		UNITS
Maximum average forward current	I <sub>F(AV)</sub>	$I_{F(AV)}$ $T_{C} = 92 \text{ °C}, 180^{\circ} \text{ conduction half sine wave}$		
Maximum peak one cycle non-repetitive surge current		10 ms sine pulse, rated V <sub>RRM</sub> applied 1100		А
	IFSM	10 ms sine pulse, no voltage reapplied	1250	
Maximum I <sup>2</sup> t for fusing I <sup>2</sup>		10 ms sine pulse, rated V <sub>RRM</sub> applied	5000	A <sup>2</sup> s
	1-1	10 ms sine pulse, no voltage reapplied	7000	A-S
Maximum I <sup>2</sup> $\sqrt{t}$ for fusing	l²√t	t = 0.1 ms to 10 ms, no voltage reapplied 70 000 $A^2\sqrt{s}$		A²√s

ELECTRICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum forward voltage drop	V <sub>FM</sub>	80 A, T <sub>J</sub> = 25 °C		1.35	V
Forward slope resistance	r <sub>t</sub>	T <sub>J</sub> = 150 °C		4.03	mΩ
Threshold voltage	V <sub>F(TO)</sub>			0.87	V
Maximum reverse leakage current		T <sub>J</sub> = 25 °C	V <sub>B</sub> = Rated V <sub>BBM</sub>	0.1	mA
Maximum reverse leakage current	IRM	T <sub>J</sub> = 150 °C	VR - naieu VRRM	12	

RECOVERY CHARACTERISTICS					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	· •
Reverse recovery time	t <sub>rr</sub>	l⊨ at 80 A <sub>pk</sub>	480	ns	
Reverse recovery current	I <sub>rr</sub>	l <sub>F</sub> at 80 A <sub>pk</sub> 25 A/µs	7.1	А	
Reverse recovery charge	Q <sub>rr</sub>	25 °C	2.1	μC	$\frac{\text{dir}}{\text{dt}}$
Snap factor	S		0.5		I IRM(REC)

THERMAL - MECHANICAL SPECIFICATIONS					
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction and storage temperature range		T <sub>J</sub> , T <sub>Stg</sub>		- 40 to 150	°C
Maximum thermal resist junction to case	ance,	R <sub>thJC</sub>	DC operation	0.35	
Maximum thermal resistance, junction to ambient		R <sub>thJA</sub>		40	°C/W
Typical thermal resistance case to heatsink	ce,	R <sub>thCS</sub>	Mounting surface, smooth and greased	0.2	
				6	g
Approximate weight	Approximate weight			0.21	oz.
Mounting torque minimum maximum				6 (5)	kgf ⋅ cm
				12 (10)	(lĎf ⋅ in)
Marking davias				80APF10	
Marking device			Case style TO-247AC	80APF12	

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## VS-80APF1.PbF Series, VS-80APF1.-M3 Series

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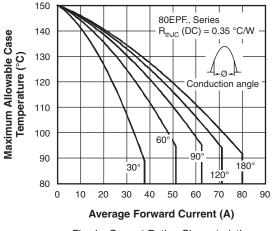


Fig. 1 - Current Rating Characteristics

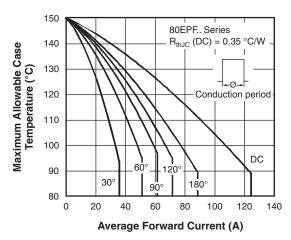


Fig. 2 - Current Rating Characteristics

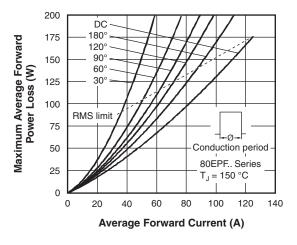


Fig. 3 - Forward Power Loss Characteristics

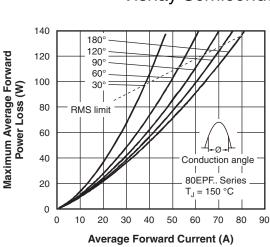
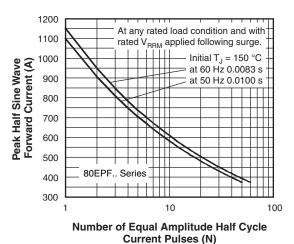
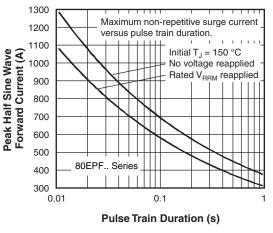


Fig. 4 - Forward Power Loss Characteristics









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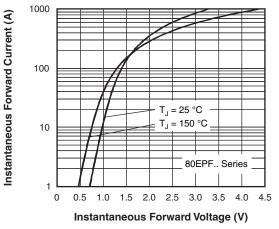
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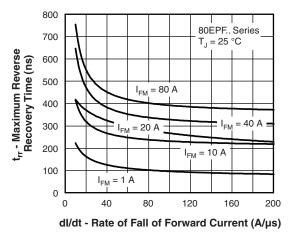


Fig. 8 - Recovery Time Characteristics,  $T_J = 25 \ ^{\circ}C$ 

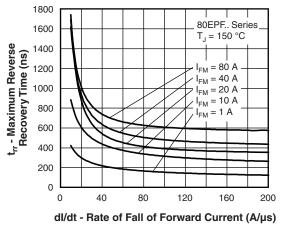


Fig. 9 - Recovery Time Characteristics,  $T_J = 150 \ ^{\circ}C$ 

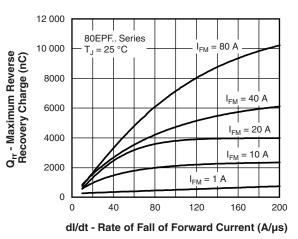
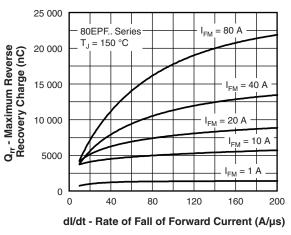


Fig. 10 - Recovery Charge Characteristics,  $T_J = 25 \ ^{\circ}C$ 



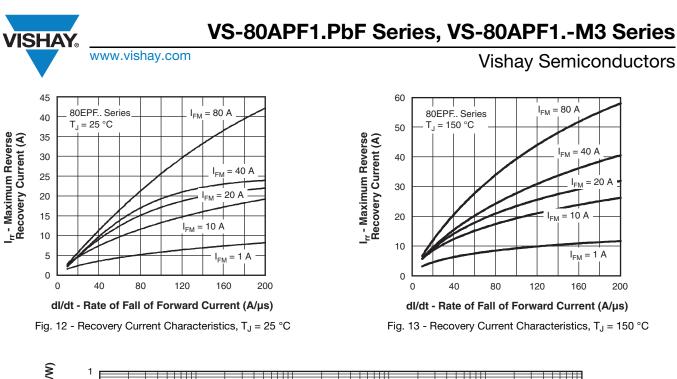


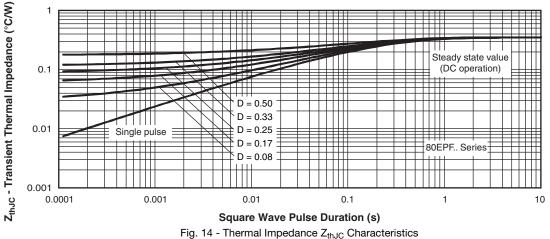
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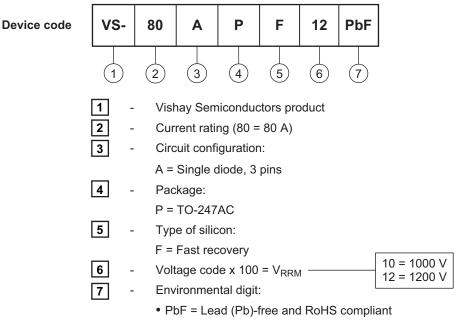


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### **ORDERING INFORMATION TABLE**



• -M3 = Halogen-free, RoHS compliant and terminations lead (Pb)-free

ORDERING INFORMATION (Example)						
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION			
VS-80APF10PbF	25	500	Antistatic plastic tubes			
VS-80APF10-M3	25	500	Antistatic plastic tubes			
VS-80APF12PbF	25	500	Antistatic plastic tubes			
VS-80APF12-M3	25	500	Antistatic plastic tubes			

LINKS TO RELATED DOCUMENTS				
Dimensions www.vishay.com/doc?95223				
Part marking information	TO-247AC PbF	www.vishay.com/doc?95226		
Part marking information	TO-247AC -M3	www.vishay.com/doc?95007		

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